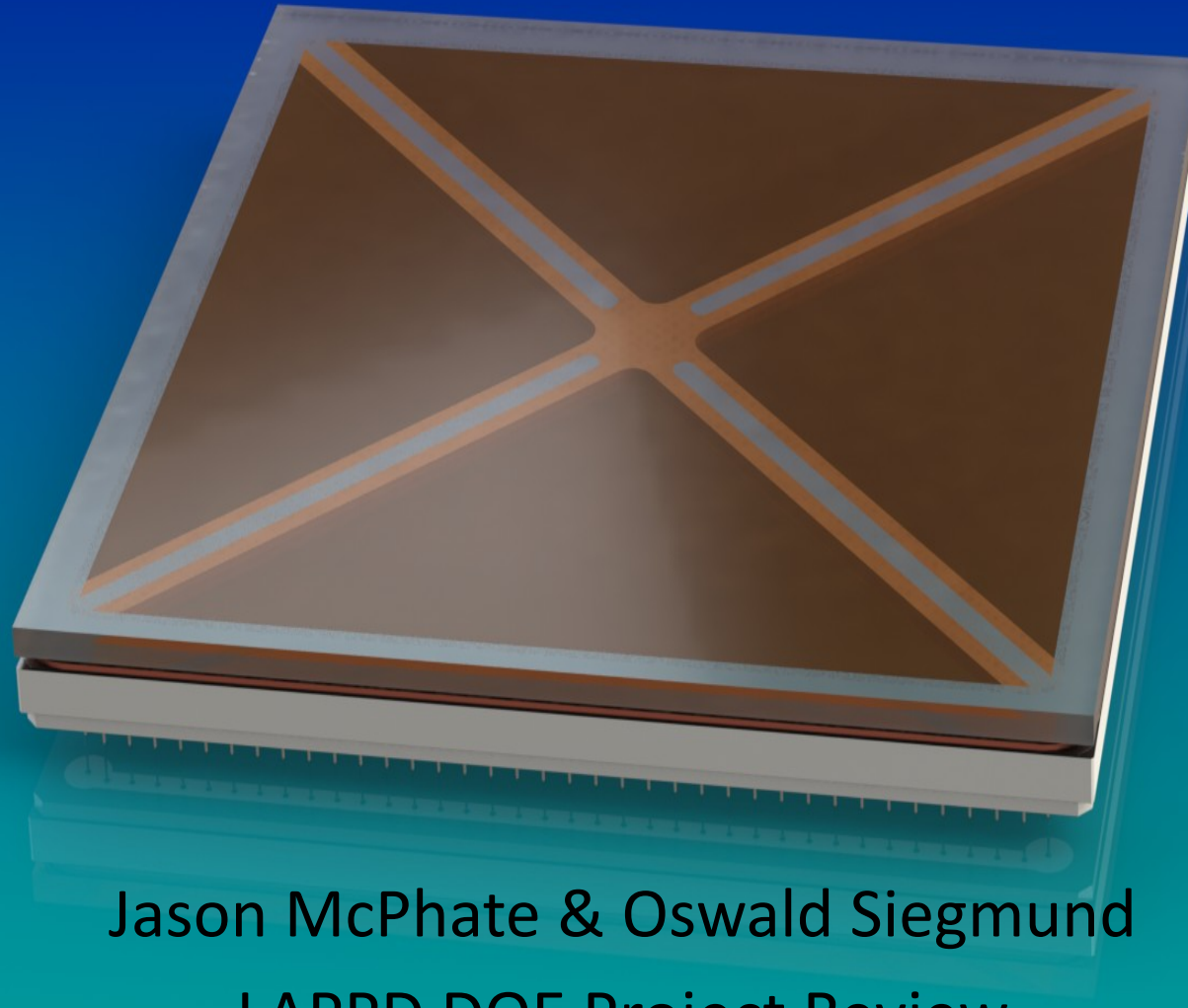




# LAPPD Ceramic Package Design, Flow, & Status



Jason McPhate & Oswald Siegmund

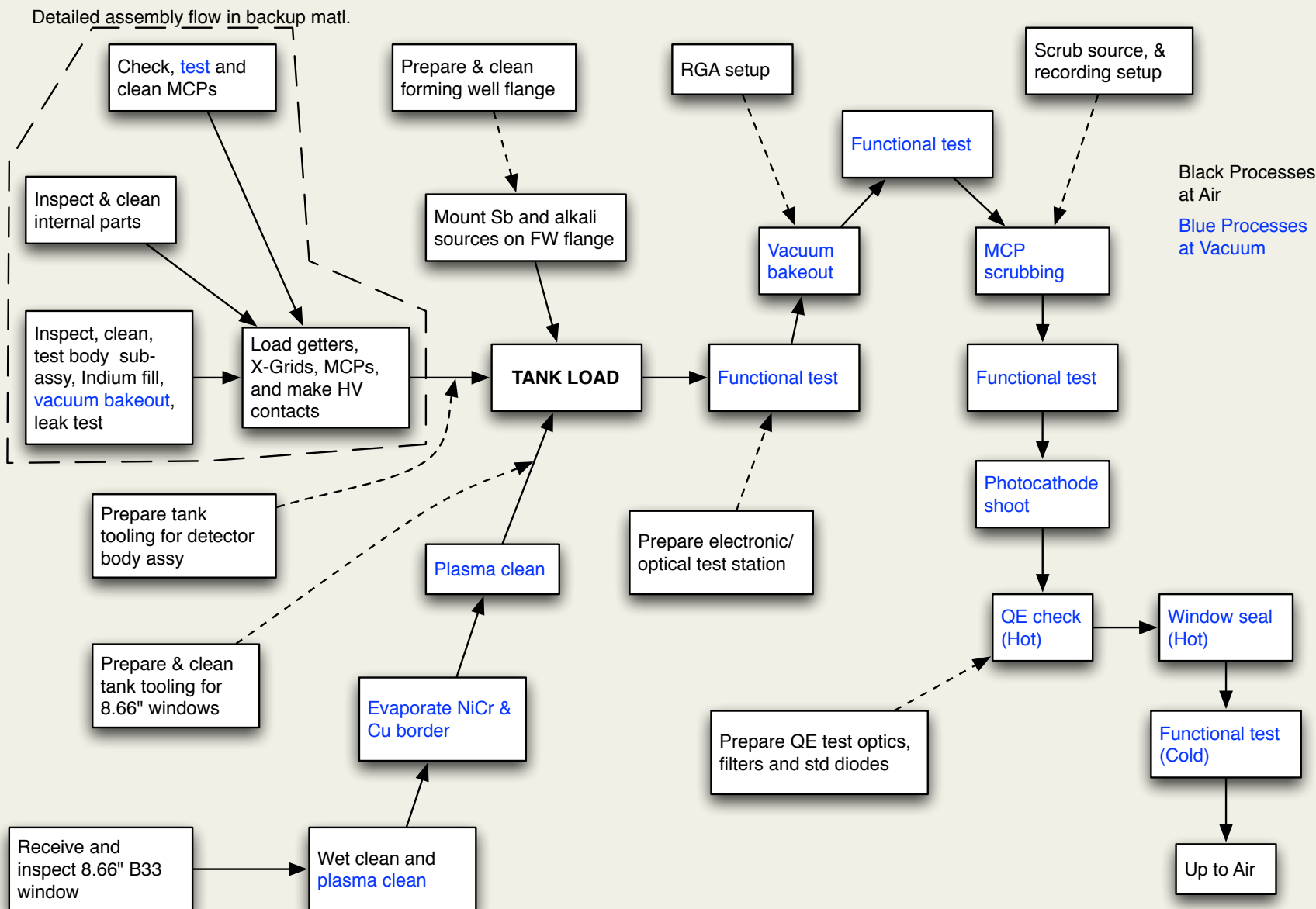
LAPPD DOE Project Review

18 December 2012





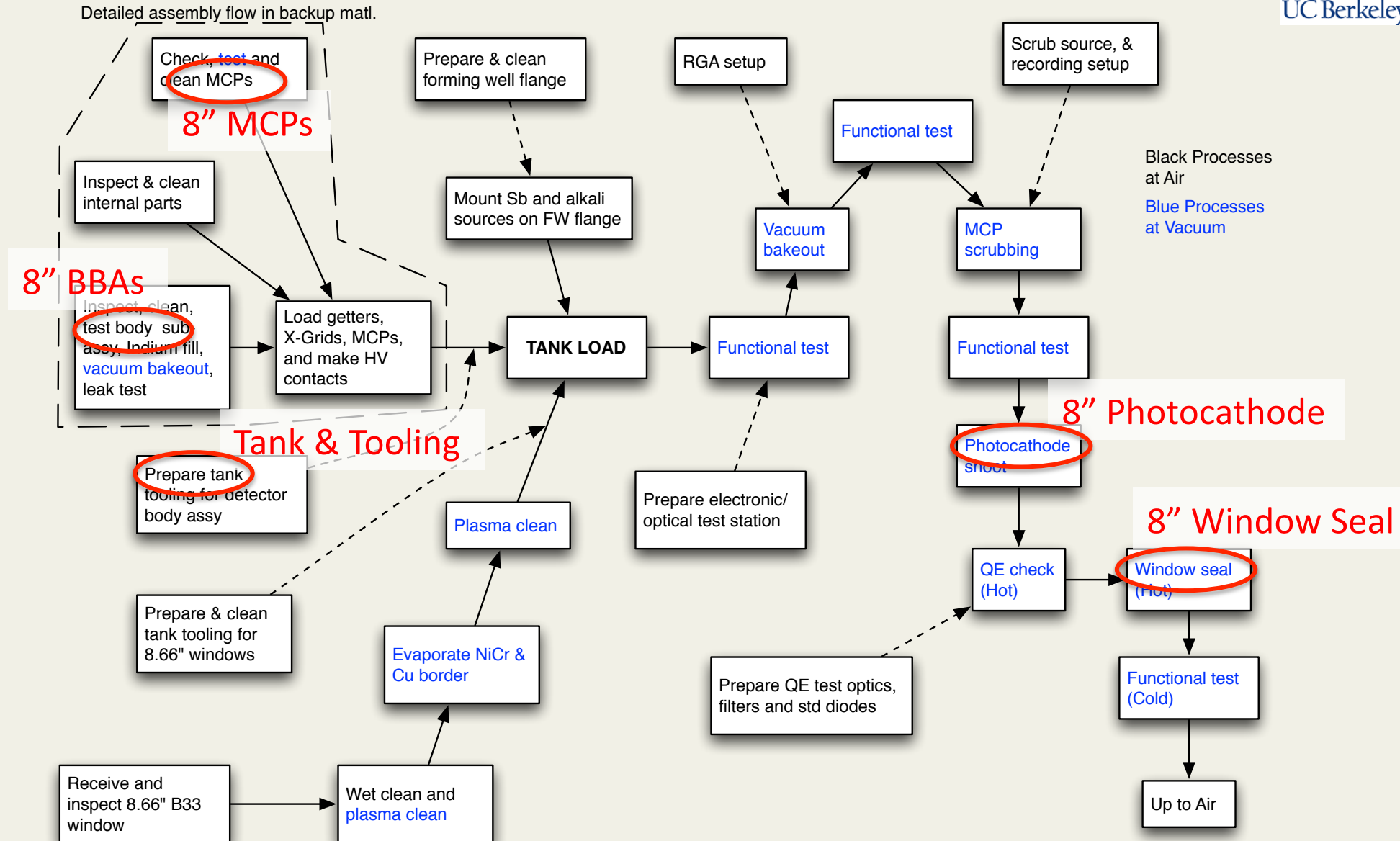
# 8" Tube Process Flow







# 8" Tube Process Flow







# Critical Path Items / Enabling Technologies



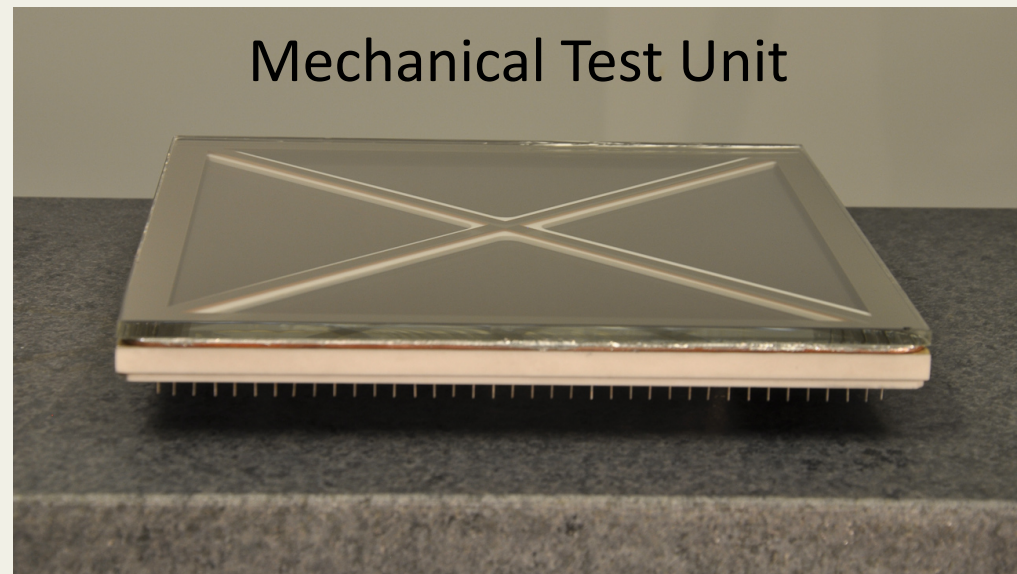
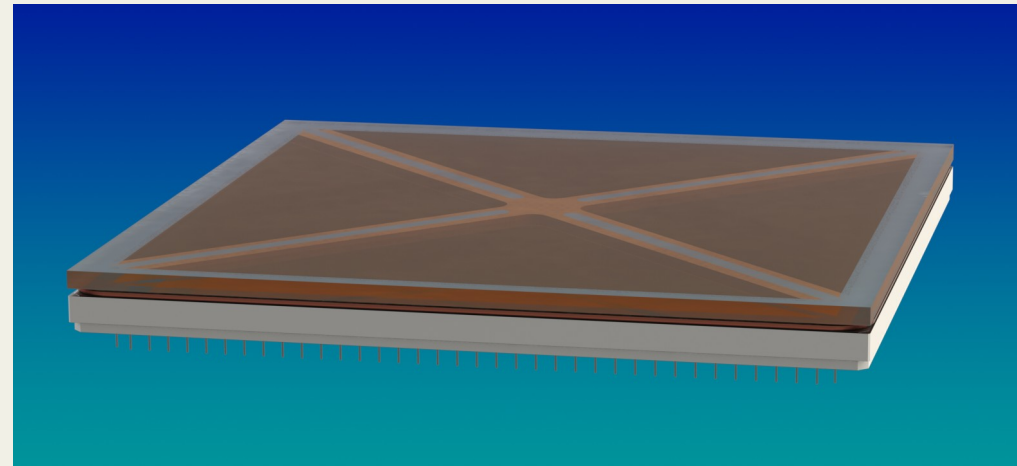
- Leak tight 8" package (ceramic or glass)
  - He leak rates below detection limit ( $<10^{-10}$  std.cc/sec)
  - Compatible with tube processing; clean and robust
- 8" ALD MCPs (Wetstein and Siegmund talks on MCPs)
  - Beyond being functional, should be: robust, low outgassing, relatively uniform in gain/response, good lifetime behavior, and compatible with tube processing
- 8" Photocathode (Siegmund talk on photocathodes)
  - Needs to be compatible with tube process; transfer type PC, and robust to hot seal technique used at UCB
  - Good QE with reasonable uniformity over active area
- 8" Hermetic Seal
  - Occurs in vacuum (hot seal in the case of UCB)
  - Challenging because of its size and square shape
- Processing system
  - Large enough to handle 8" tube parts, small enough to fit within our existing oven
  - Internal tooling for manipulation and translation of 8" window
  - Flexibility to work with either ceramic or glass package (or future customized packages) with minimal modification





# Ceramic Package Design Overview

- Use “standard” sealed tube materials and processing
- Ceramic brazed body with Cu indium well
  - Signals and HV passed through the anode on Kovar pins
- 5mm thick borosilicate (Schott B33) window
- $\text{Na}_2\text{KSb}$  bialkali photocathode
- Hot seal (InBi alloy)
- “X” shaped internal support structure
- 8.66” square, ~0.68” thick (including window)

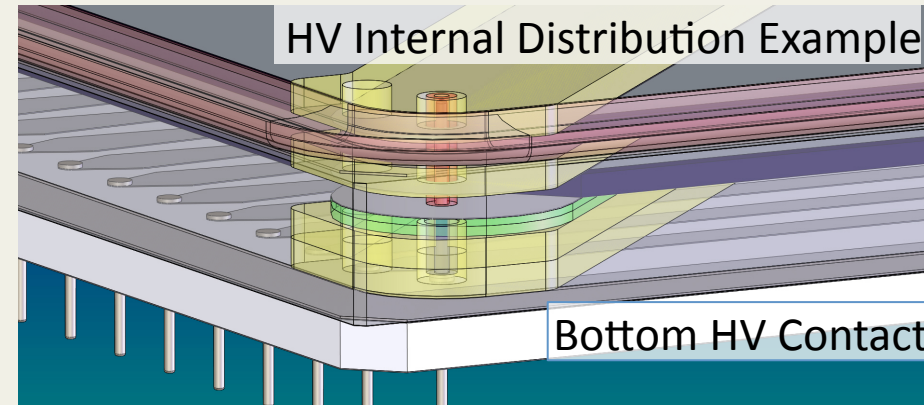




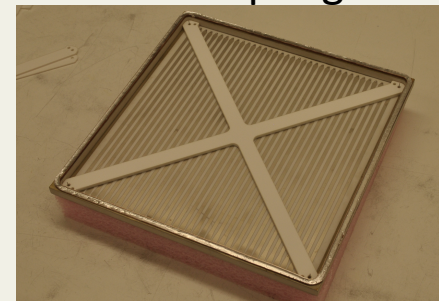


# Internal Stack-Up

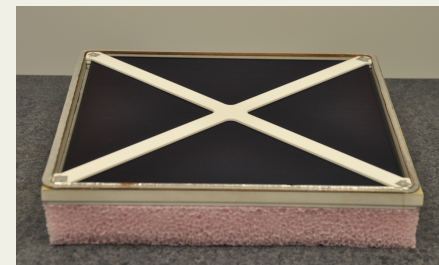
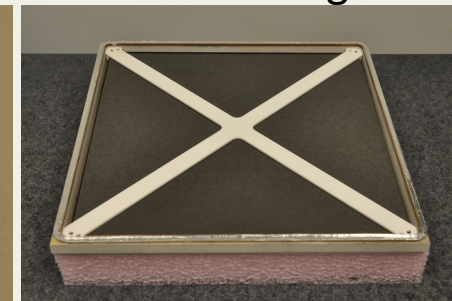
- Large area requires internal support structure to prevent window/anode cracking under atmospheric pressure load
- Desire to support without creating trapped spaces lead to “X” shaped support structures
- Combination of insulating ceramic X-grids and stainless X-shims
- X-grids isolate HV potentials while X-shims facilitate HV distribution (and stack height adjustment)
- Top X-grid serves to retain entire stack during processing
- Total internal stack height is .003” to .006” *below* the top of the Cu well – to ensure window seal



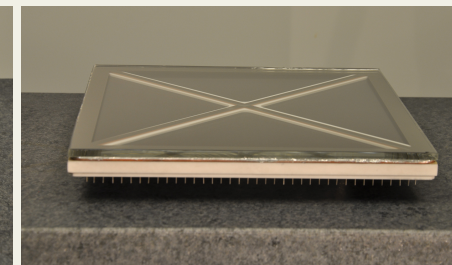
Anode Gap X-grids



Inter-MCP X-grid



Cathode Gap X-grid



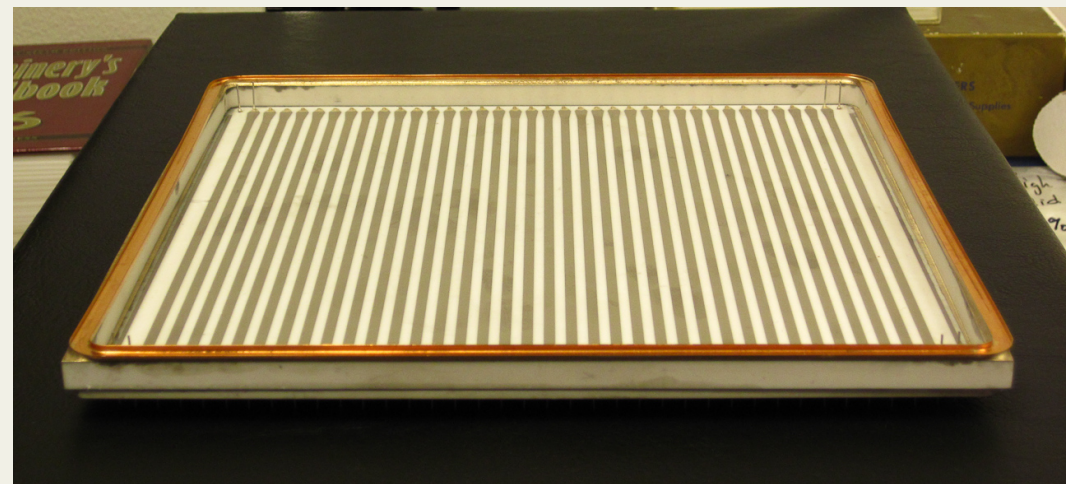
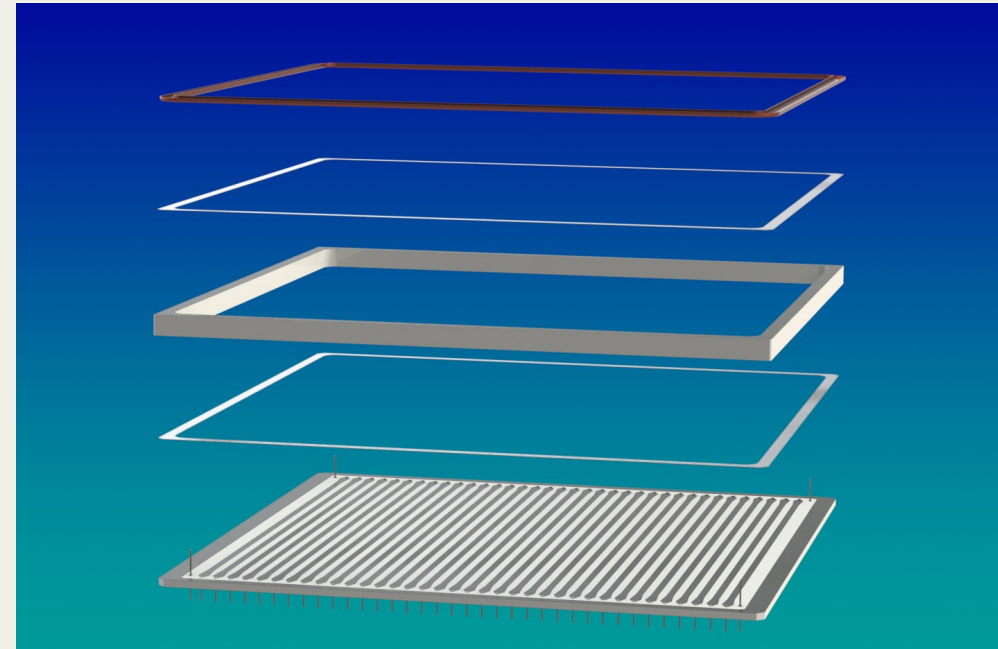
Mech. Test Unit





# Ceramic Brazed Body Assembly

- All materials refractory or metal and proven for vacuum tube manufacturing
- High-temp metallized ceramic anode with Kovar feedthrough pins
- Ceramic sidewall frame
- Indium seal well is stamped from OFE copper (used for optimal indium wetting and ductility)
- Only two braze joints (save for the pins), using InCuSil braze alloy
- Large CTE mismatch between Cu and ceramic, but the Cu is very ductile and does not over-stress the ceramic

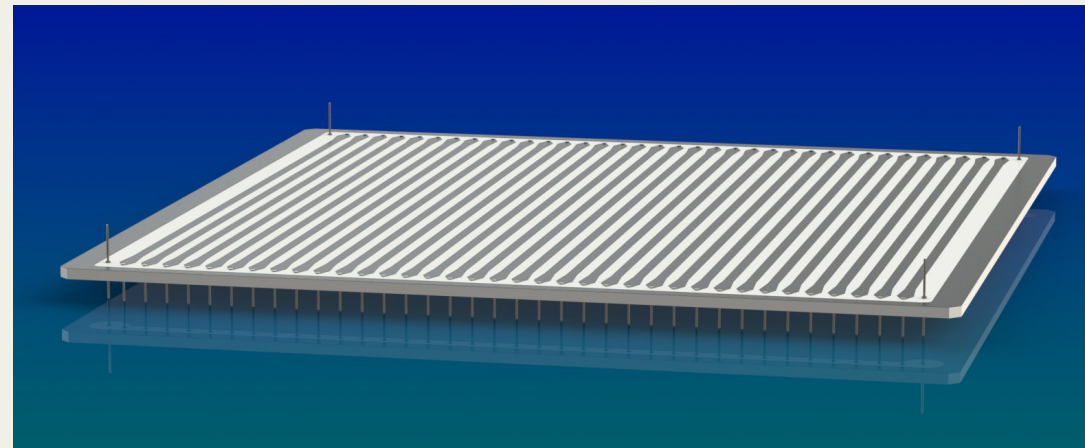
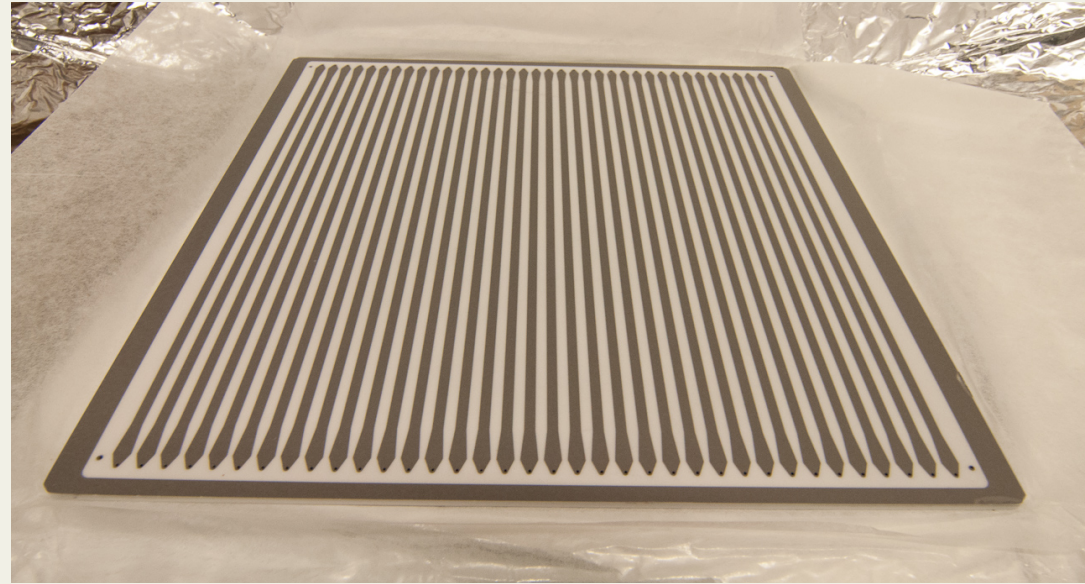






# Ceramic Anode

- Substrate is .100" thick 96% alumina
- High-temp metallization
- 36 signal strips inside
- Solid ground plane outside
- Headed Kovar pins for signal and HV feedthrough
- HV pins are double-ended to distribute HV vertically within the tube – one in each corner
- Pins (76 in total) brazed into anode one of two ways
  - CuSil braze prior to body braze (current preferred method)
  - InCuSil braze simultaneously with body braze







# A Brief History of the Ceramic Package Brazing Challenges



- Initial brazes were  $H_2$  furnace, CuSil alloy with Kovar indium well resulted in cracked ceramic sidewall
  - Kovar a better (but not perfect) CTE match to alumina
  - Kovar too strong relative to ceramic → ceramic cracking
  - Also not getting complete braze alloy melt
- Switched to Cu well and InCuSil alloy
  - Still imperfect braze alloy melt
  - Not much helpful feed back from brazing vendor
- Switched braze vendor (vacuum brazing)
  - Much more responsive and proactively involved in process
- Two methods employed to-date at new vendor
  - All-in-one: Single InCuSil braze (pins to anode, anode and well to sidewall in one single braze process) – All assemblies leaked, particularly at pins.
  - Two-step: CuSil to braze pins into anode, then InCuSil to braze anode-sidewall-well assembly – Current process resulting in progressively better assemblies





# Two-Step Brazing Process

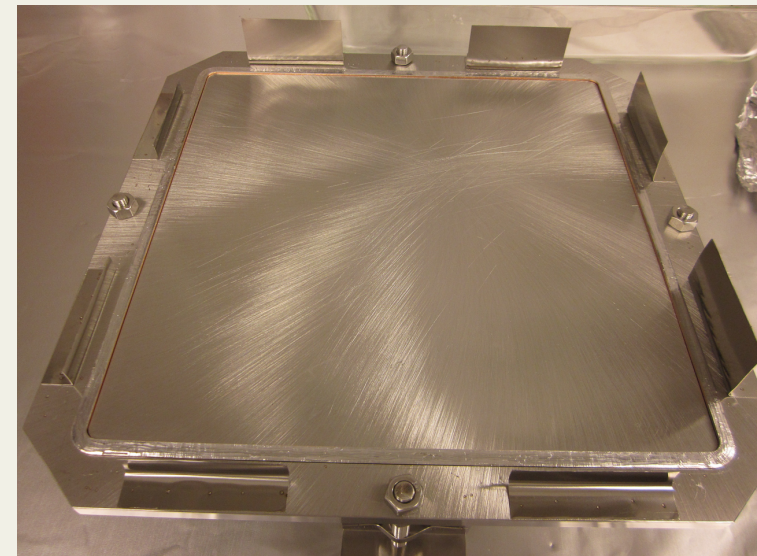
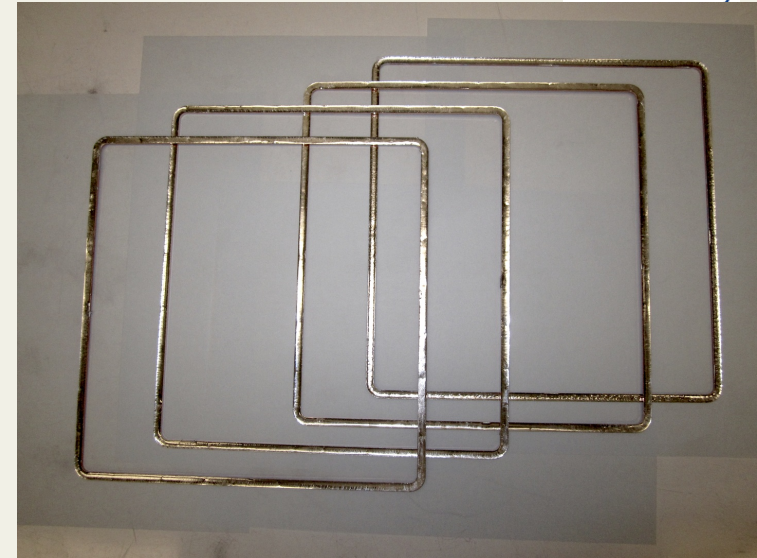
- Pins brazed into anode first
  - CuSil braze alloy –  $\sim 850^{\circ}\text{C}$  process temperature
  - Stresses are minimal (pins are small) – Multiple re-braze runs possible
  - Mitigates risk at the incursion of increased expense
  - Three consecutive leak-tight anode-pin assemblies since switching to this method
- Body brazed using pre-pinned anode assembly
  - InCuSil braze alloy –  $\sim 750^{\circ}\text{C}$  process temp, so no re-melt of pin braze CuSil alloy
  - Only one bite at this apple – Re-brazing seems to result in cracked parts (at least the one time we tried)
- Improved final assemblies
  - Prior to using the two-step process, assemblies had gross leaks – particularly at the pins
    - Several process modifications to the All-in-One braze did not significantly improve the results
  - The two stage process immediately resulted in assemblies that were much closer to leak tight and incremental progress has been made since
    - The first such assembly had four leaks in the  $10^{-7}$  to  $10^{-6}$  std. cc/sec regime
    - Latest has a single leak on one joint, other joint is leak tight
    - Further process modification is being made to resolve these smaller leaks





# 8" Hot Seal on Cu Well

- Indium loaded into free Cu well (not brazed to ceramic wall)
- Scraped to remove surface oxides
- Vacuum baked to outgas indium and float internally trapped oxides
- Scraped again to remove oxides
- Installed in grooved plate (provided lateral, but not vertical constraint)

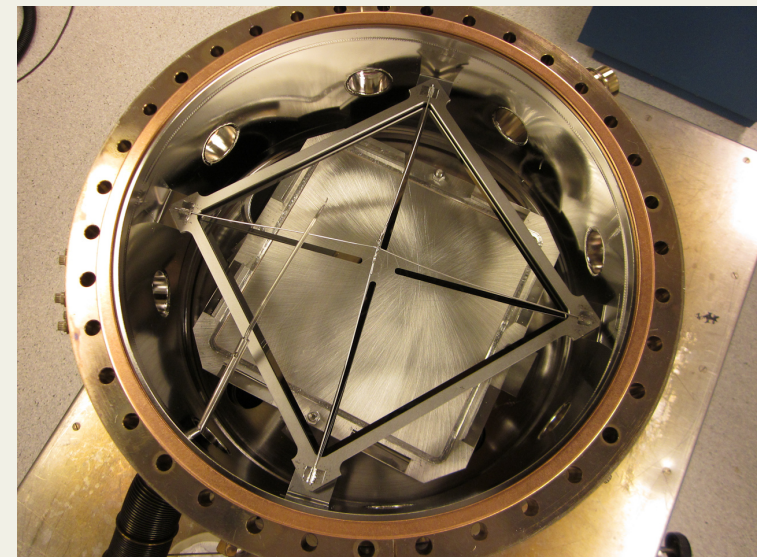
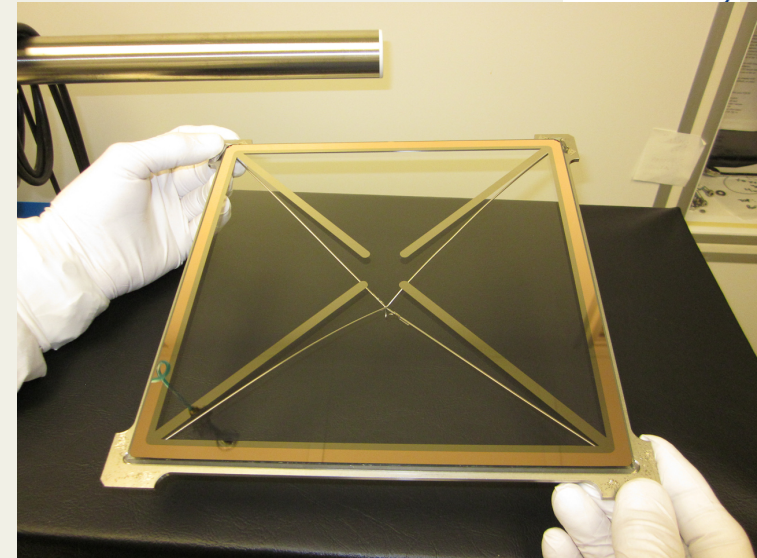






# 8" Hot Seal on Cu Well

- 8.66" Borofloat B33 window evaporated with NiCr + Cu
- Installed into 8" photocathode test tank
- Heated in vacuum (160°C) and seal attempted
- Post-seal the chamber was cooled and vented
- Same process used during tube processing seal
- Good indium wetting to window (promising), but...

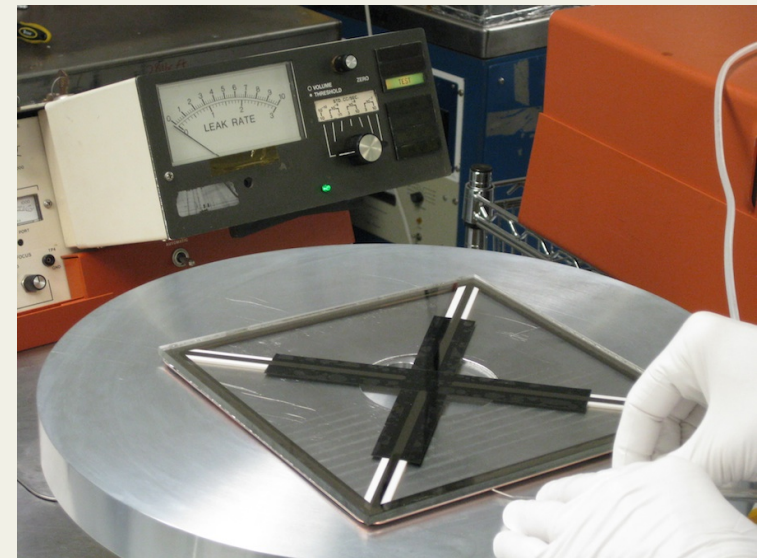
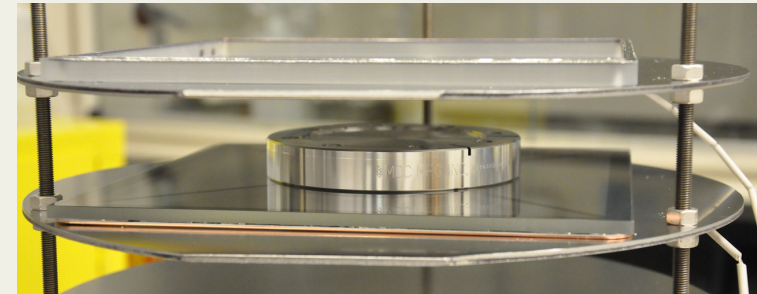
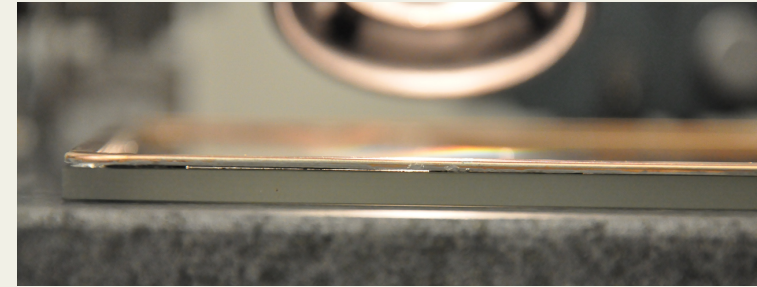






# 8" Hot Seal on Cu Well

- Copper deformed from flat → Significant gapping between window and copper
- Laterally restrained, but vertically free  
Cu well was not representative of the final assembly (where the Cu is affixed to the flat ceramics)
- Re-heated in vacuum *without* lateral constraint and with weight to re-induce flatness in Cu well.
- Resulting assembly is leak tight to  $<10^{-10}$  std.cc/sec of He
- Window supported with X-grid during leak test
  - No window or X-grid breakage

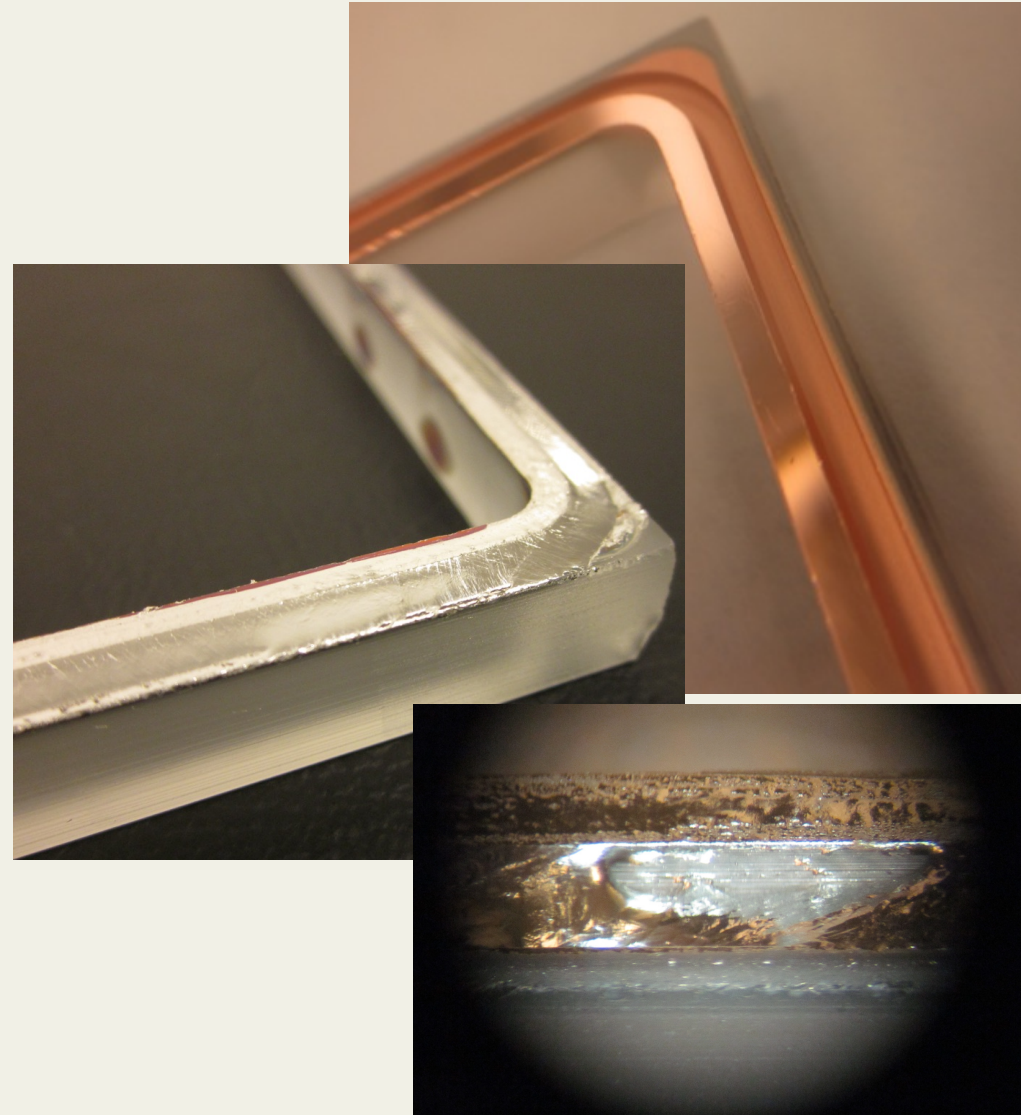






# 8" Grooved Glass Sidewall

- Groove machined into glass sidewall at UChicago
- NiCr and Cu evaporated into groove ( $\sim 1000\text{\AA}$  Cu)
- Indium filled and scraped
- Vacuum baked
- Cu scavenged by In during vacuum bake resulting in several pockets of bare glass
- Next article:
  - Better cleaning (plasma clean) prior to evaporation
  - Thicker NiCr and Cu to prevent loss of layer

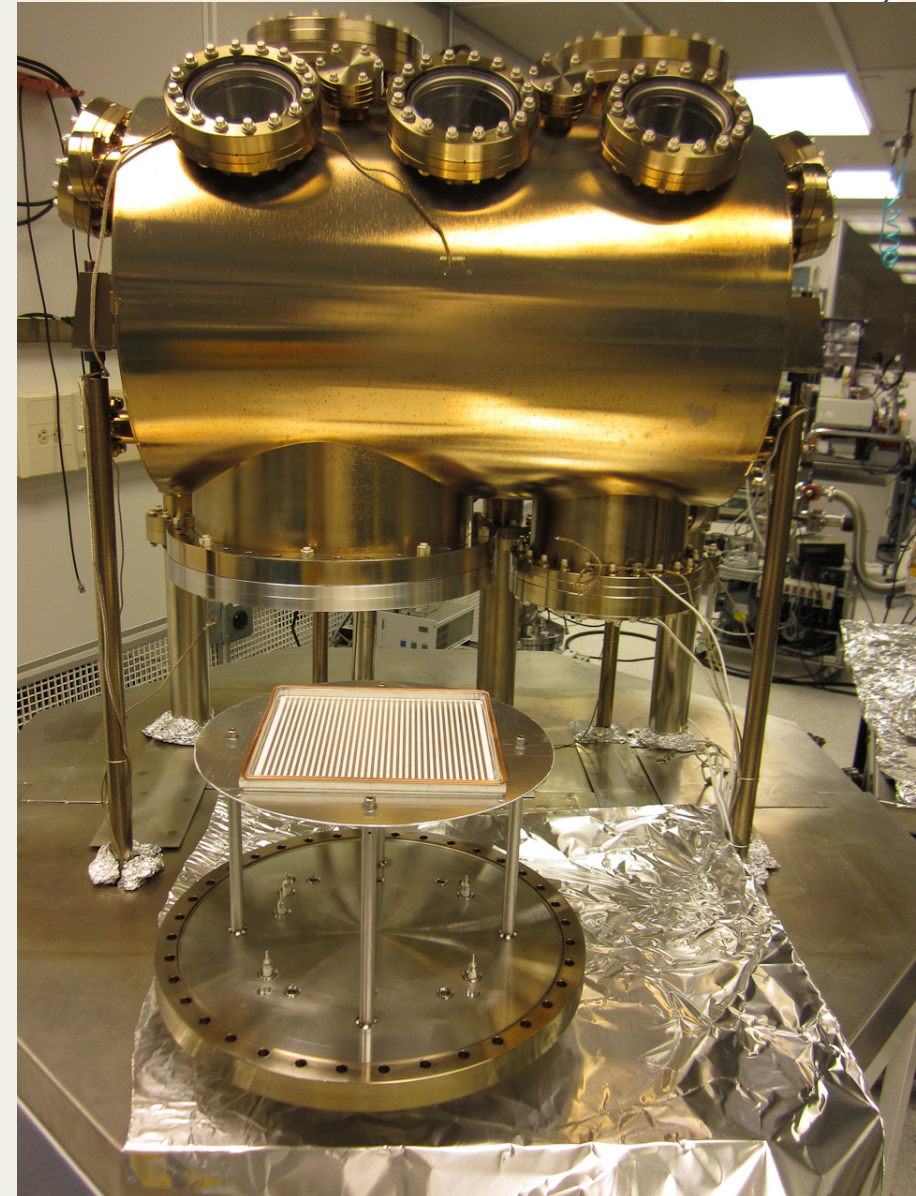






# Large Process Chamber

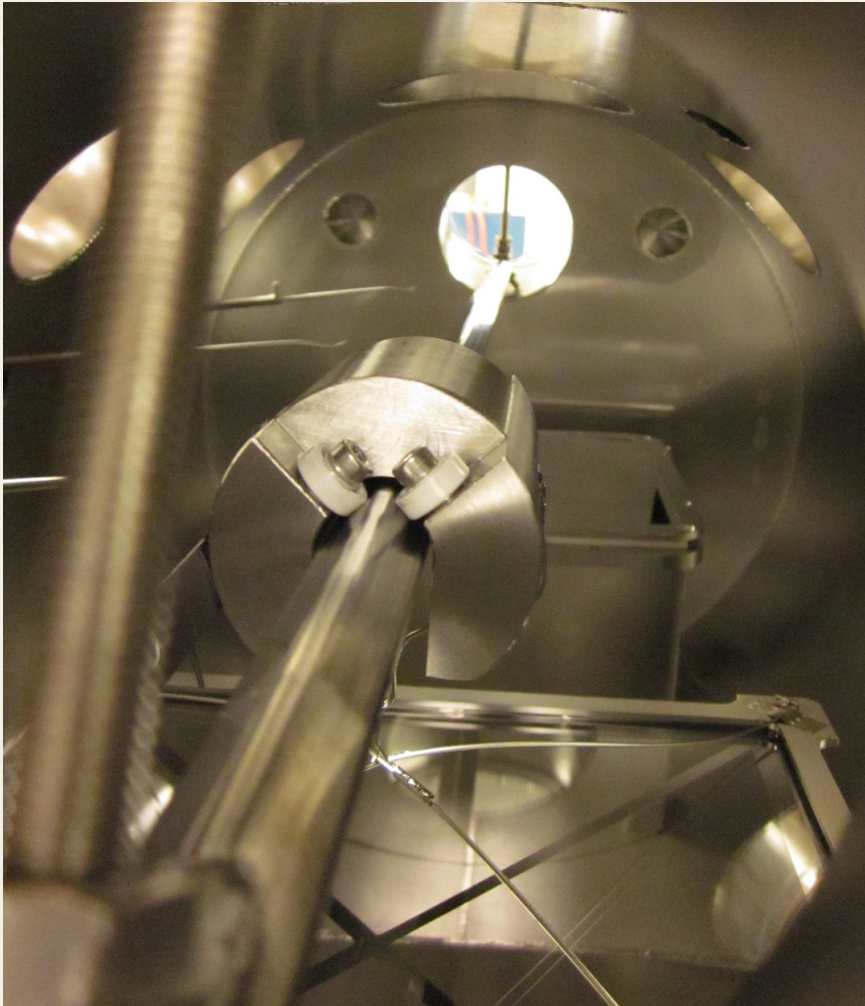
- 8" sealed tube process chamber is fully commissioned
- Base pressure in the low  $10^{-10}$  torr range
- Internal manipulation tooling complete and installed
- Photocathode deposition tooling complete and installed
- First 8" photocathode completed (process optimization next)
- Detector flange and support platform fabrication complete (need to make signal/HV contacts)



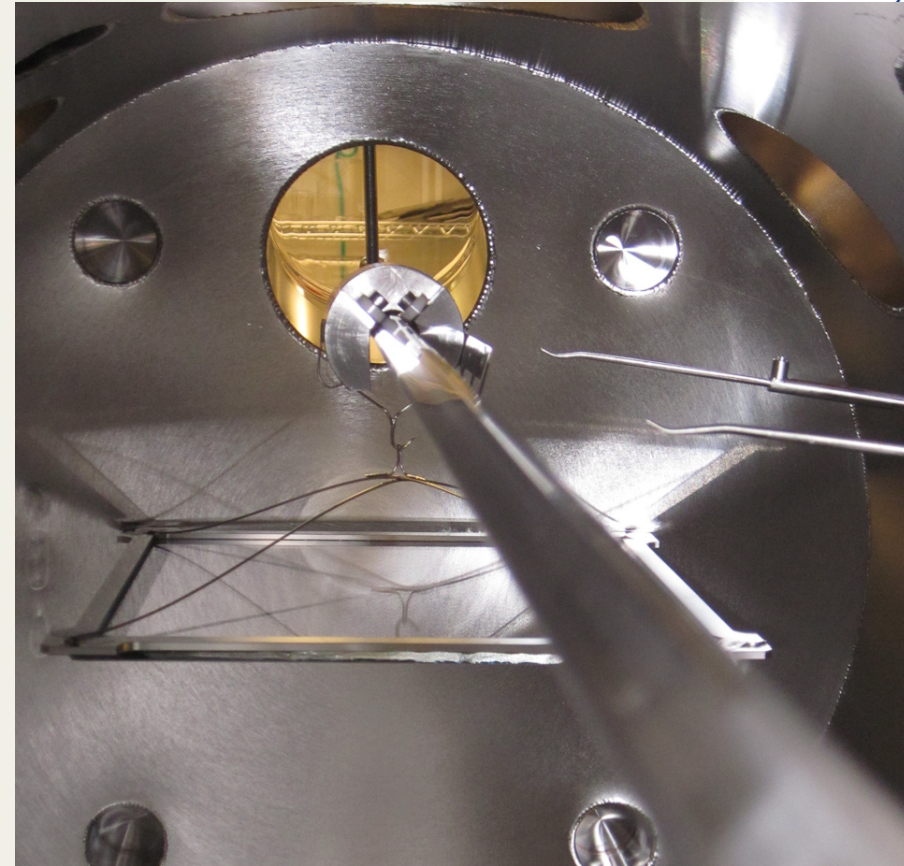




# Large Process Chamber



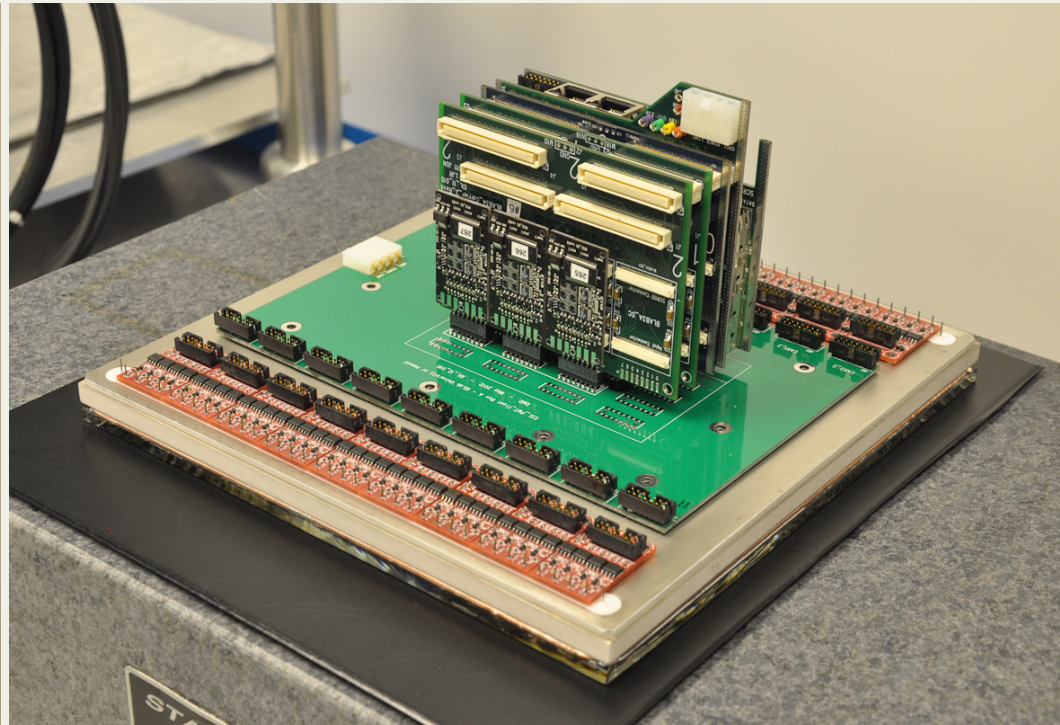
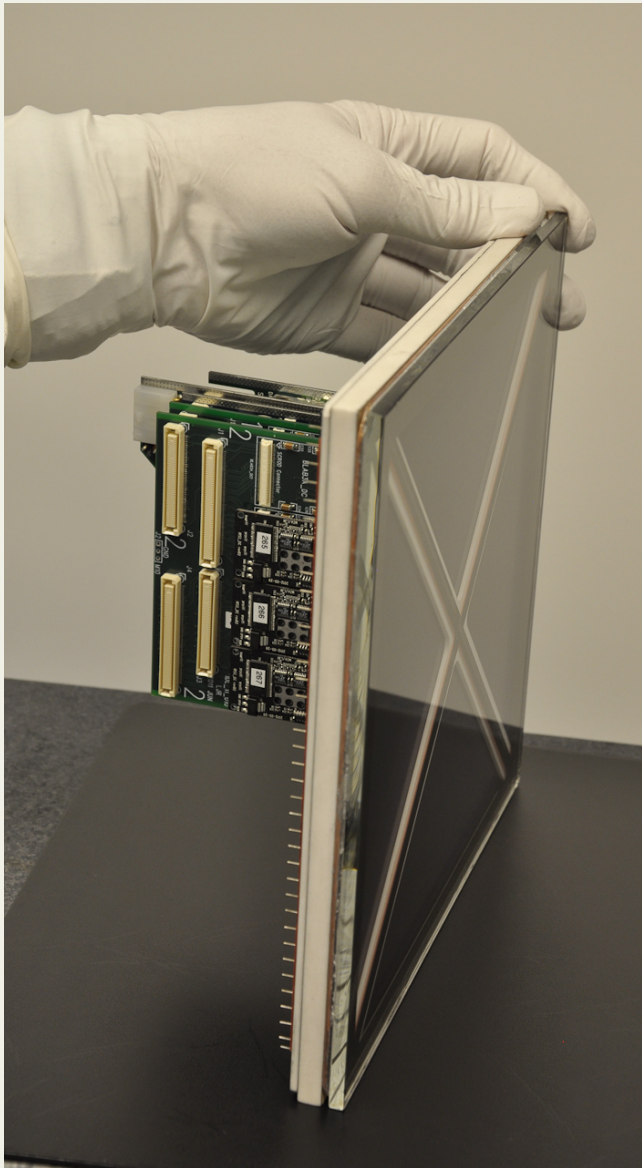
Looking down the window translation mechanism toward the photocathode forming well at the far end.



Window for 1<sup>st</sup> PC hanging on translation shuttle. Manipulation is performed with the wobble sticks at right.



# Ceramic Package Electronics



- Readout electronics for the ceramic package provided by U of Hawaii (Varner talk on Electronics)
- Based on Belle-II iTOP readout electronics
- 18x 4-channel pre-amplifier boards
- 9x 8-channel analog to digital daughter cards
- 1x interface board and 1x power board
- Ready for testing
- Need ceramic package based demountable detector or tube to test





# Near-Term Plans

- Fabricate brazed bodies from piece parts currently in process (six or seven more assemblies)
- Optimize photocathode in large process chamber
- Design & fabricate a brazed body based demountable detector for MCP & electronics testing
- Continue verification of glass package for processing in UCB system
- Begin tube fabrication upon arrival of first leak tight brazed body (or verification of glass package)





# Longer-Near-Term Plans & Goals

- Continue production of sealed tubes at UCB
- Optimize ceramic package design
- Procure and process piece parts to support LAPPD 3 year goals
- Design and fabricate tooling for glass package processing
- Investigate potential cost saving modifications to the ceramic package (e.g., frit bonding the anode to a grooved ceramic sidewall)